

As shown in the data sheet, this approach does not require the use of transformers or tuned circuits. The balanced modulator function is achieved with matched transistors in the differential amplifiers, with the modulating signal controlling the emitter current of the “diff-amps.” The carrier signal is applied to switch the diff-amps’ bases, resulting in a mixing process with the mixing product signals out of phase at the collectors. This is an extremely versatile device since it can be used not only as a balanced modulator but also as an amplitude modulator, synchronous detector, FM detector, or frequency doubler.



## 4-3 SSB FILTERS

Once the carrier has been eliminated, it is necessary to cancel one of the sidebands without affecting the other one. This requires a sharply defined filter, as Figure 4-3 helps illustrate. Voice transmission requires audio frequencies from about 100 Hz to 3 kHz. Therefore, the upper and lower sidebands generated by the balanced modulator are separated by 200 Hz, as shown in Figure 4-3.

The required  $Q$  depends on the center or carrier frequency,  $f_c$ ; the separation between the two sidebands,  $\Delta f$ ; and the desired attenuation level of the unwanted sideband. It can be calculated from

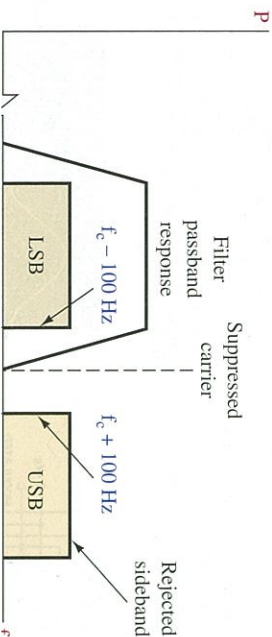
$$Q = \frac{f_c(\log^{-1} \text{dB}/20)^{1/2}}{4\Delta f} \quad (4-1)$$

where dB is the suppression of the unwanted sideband.

### Example 4-1

Calculate the required  $Q$  for the situation depicted in Figure 4-3 for

- A 1-MHz carrier and 80-dB sideband suppression.
- A 100-kHz carrier and 80-dB sideband suppression.



### Solution

$$\begin{aligned} Q &= \frac{f_c(\log^{-1} \text{dB}/20)^{1/2}}{4\Delta f} \\ &= \frac{1 \text{ MHz}(\log^{-1} 80/20)^{1/2}}{4 \times 200 \text{ Hz}} = \frac{1 \times 10^6(10^3)^{1/2}}{800} \\ &= \frac{1 \times 10^8}{8 \times 10^2} = 125,000 \end{aligned} \quad (a)$$

$$\begin{aligned} Q &= \frac{100 \text{ kHz}(\log^{-1} 80/20)^{1/2}}{4 \times 200 \text{ Hz}} \\ &= \frac{10^7}{8 \times 10^2} = 12,500 \end{aligned} \quad (b)$$

A practical consequence of the preceding example is that the would be generated around the lower 100-kHz carrier in conjunction with the filter. Then, after removing one sideband, an additional frequency range is employed to get the sideband up to the desired frequency range accomplished with a mixer circuit.

Both SSB transmitters and receivers require selective bandpass region of 100 to 500 kHz. In receivers a high order of adjacent channels required if channels are to be closely spaced to conserve spectrum space used, therefore, must have very steep skirt characteristics (fast roll-off), bandpass characteristic to pass all frequencies in the band equally well. requirements are met by crystal filters, ceramic filters, and mechanical filters. It is often used in TV and radar applications and is treated in Chapter 11. It is often used in TV and radar applications and is treated in Chapter 11. It is often used in TV and radar applications and is treated in Chapter 11.

## Crystal Filters

The crystal filter is commonly used in single-sideband systems to allow wanted sideband. Because of its very high  $Q$ , the crystal filter passes a narrow band of frequencies than the best LC filter. Crystals with a  $Q$  of 50,000 are available.

The equivalent circuit of the crystal and crystal holder is shown in Figure 4-4(a). Recall that the basics of crystal operation were introduced in Chapter 4-4(a). The components  $L_s$ ,  $C_s$ , and  $R_s$  represent the series resonant circuit of the crystal.  $C_p$  represents the parallel capacitance of the crystal holder. A very low-impedance path to the frequency to which it is resonant shunts the crystal and offers a path to other frequencies. For the crystal filter, some means must be provided to counteract the shunt impedance path to other frequencies. This is accomplished by placing an external variable capacitor in parallel with the crystal holder. This is accomplished by placing an external variable capacitor in parallel with the crystal holder. This is accomplished by placing an external variable capacitor in parallel with the crystal holder.

In Figure 4-4(b), a simple bandpass crystal filter is shown. The circuit [Fig. 4-4(b)], a simple bandpass crystal filter is shown. The circuit [Fig. 4-4(b)], a simple bandpass crystal filter is shown.